

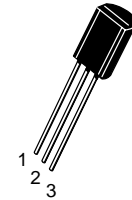
# One Watt Amplifier Transistor

## PNP Silicon

**MPS6726**  
**MPS6727**

### MAXIMUM RATINGS

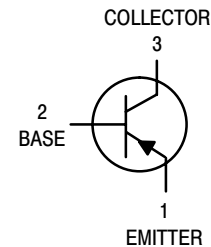
Rating	Symbol	Value	Unit
Collector–Emitter Voltage MPS6726 MPS6727	$V_{CEO}$	–30 –40	Vdc
Collector–Base Voltage MPS6726 MPS6727	$V_{CBO}$	–40 –50	Vdc
Emitter–Base Voltage	$V_{EBO}$	–5.0	Vdc
Collector Current — Continuous	$I_C$	–1.0	Adc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	1.0 8.0	Watts mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	2.5 20	Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	–55 to +150	$^\circ\text{C}$



CASE 29–05, STYLE 1  
TO–92 (TO–226AE)

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	125	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	50	$^\circ\text{C}/\text{W}$



### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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### OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ( $I_C = -10 \text{ mAdc}$ , $I_E = 0$ )	MPS6726 MPS6727	$V_{(BR)CEO}$	–30 –40	— —	Vdc
Collector–Base Breakdown Voltage ( $I_C = -100 \mu\text{Adc}$ , $I_E = 0$ )	MPS6726 MPS6727	$V_{(BR)CBO}$	–40 –50	— —	Vdc
Emitter–Base Breakdown Voltage ( $I_E = -100 \mu\text{Adc}$ , $I_C = 0$ )		$V_{(BR)EBO}$	–5.0	—	Vdc
Collector Cutoff Current ( $V_{CB} = -40 \text{ Vdc}$ , $I_E = 0$ ) ( $V_{CB} = -50 \text{ Vdc}$ , $I_E = 0$ )	MPS6726 MPS6727	$I_{CBO}$	— —	–0.1 –0.1	$\mu\text{Adc}$
Emitter Cutoff Current ( $V_{EB} = -5.0 \text{ Vdc}$ , $I_C = 0$ )		$I_{EBO}$	—	–0.1	$\mu\text{Adc}$

# MPS6726 MPS6727

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
<b>ON CHARACTERISTICS<sup>(1)</sup></b>				
DC Current Gain ( $I_C = -100\text{ mAdc}$ , $V_{CE} = -1.0\text{ Vdc}$ ) ( $I_C = -1000\text{ mAdc}$ , $V_{CE} = -1.0\text{ Vdc}$ )	$h_{FE}$	60 50	— 250	—
Collector–Emitter Saturation Voltage ( $I_C = -1000\text{ mAdc}$ , $I_B = -100\text{ mAdc}$ )	$V_{CE(sat)}$	—	-0.5	Vdc
Base–Emitter On Voltage ( $I_C = -1000\text{ mAdc}$ , $V_{CE} = -1.0\text{ Vdc}$ )	$V_{BE(on)}$	—	-1.2	Vdc

## SMALL-SIGNAL CHARACTERISTICS

Collector–Base Capacitance ( $V_{CB} = -10\text{ Vdc}$ , $I_E = 0$ , $f = 1.0\text{ MHz}$ )	$C_{cb}$	—	30	pF
Small–Signal Current Gain ( $I_C = -50\text{ mAdc}$ , $V_{CE} = -10\text{ Vdc}$ , $f = 20\text{ MHz}$ )	$h_{fe}$	2.5	25	—

1. Pulse Test: Pulse Width  $\leq 300\ \mu\text{s}$ ; Duty Cycle  $\leq 2.0\%$ .

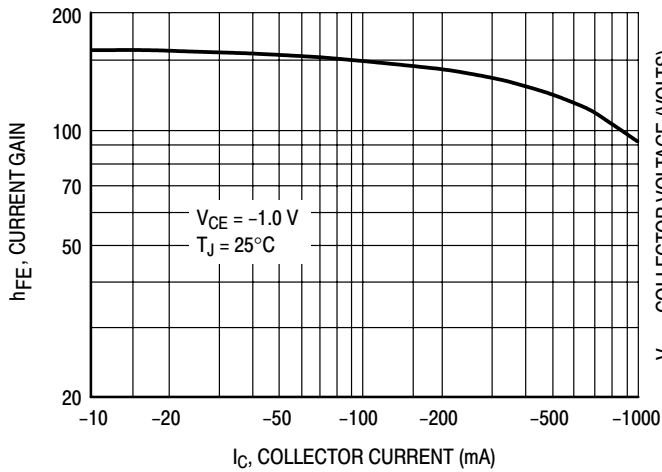


Figure 1. DC Current Gain

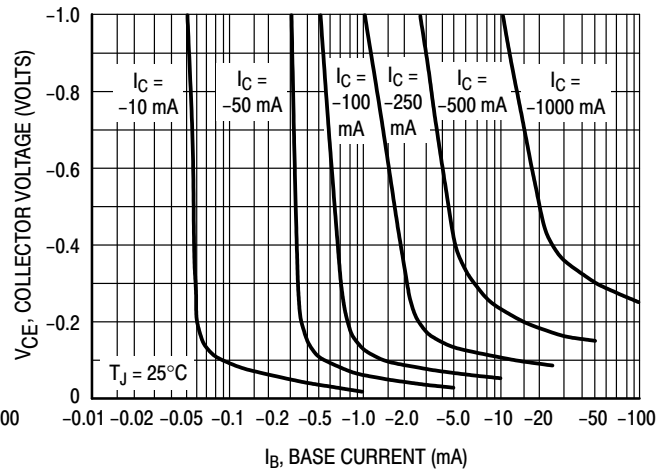


Figure 2. Collector Saturation Region

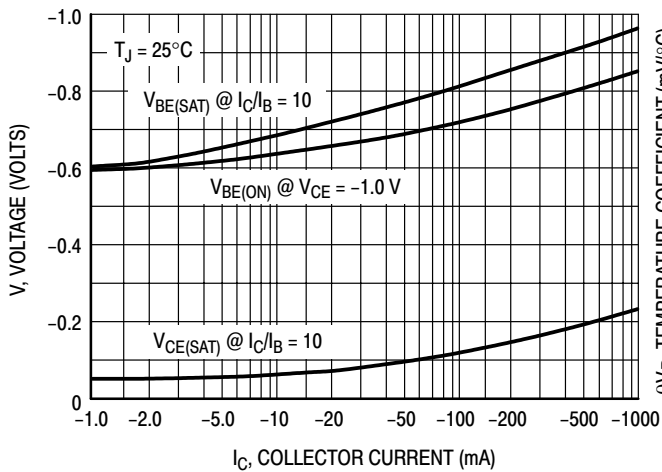


Figure 3. "ON" Voltages

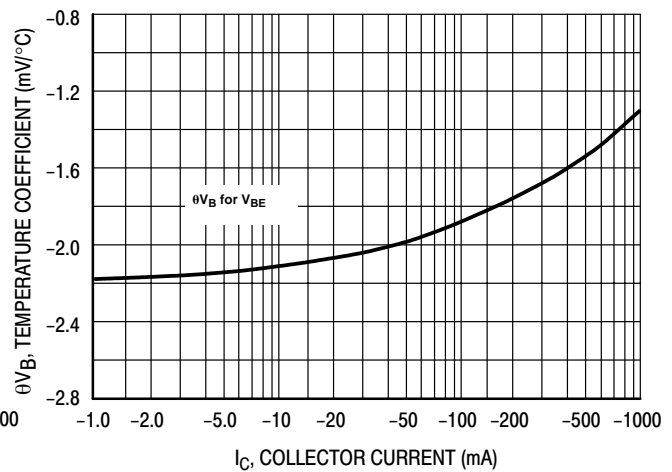


Figure 4. Temperature Coefficient

# MPS6726 MPS6727

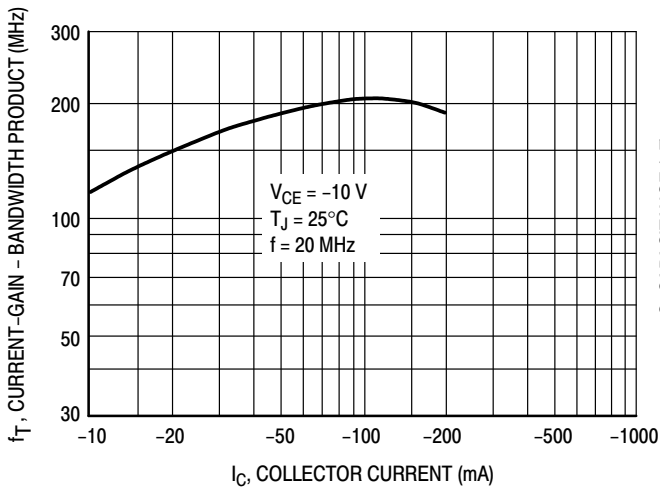


Figure 5. Current Gain — Bandwidth Product

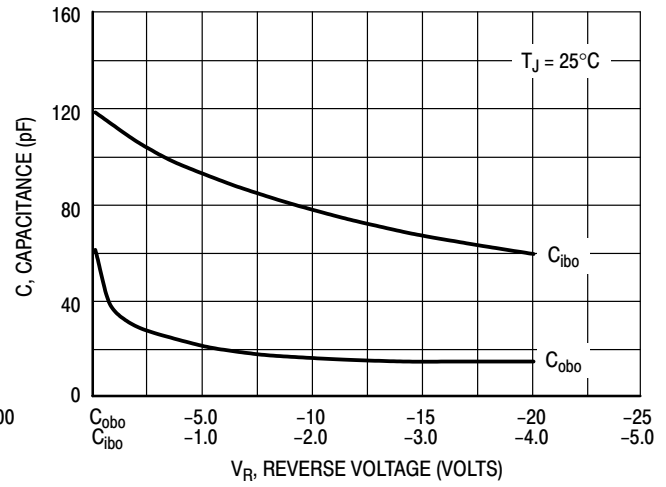


Figure 6. Capacitance

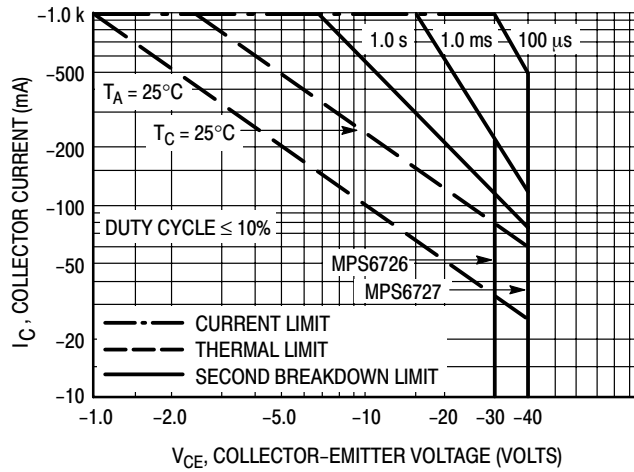
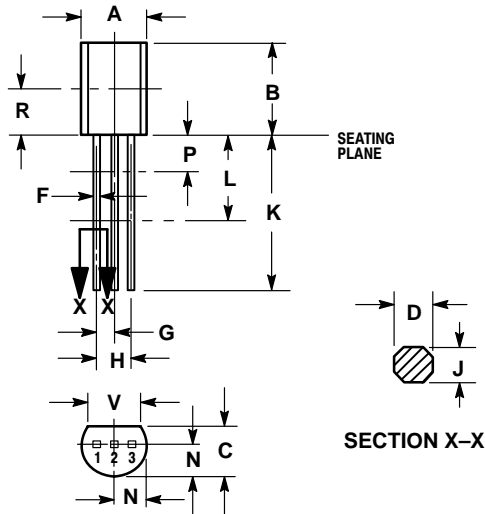


Figure 7. Active Region — Safe Operating Area

# MPS6726 MPS6727

## PACKAGE DIMENSIONS

### CASE 029-05 (TO-226AE) ISSUE AD



#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSIONS D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.44	5.21
B	0.290	0.310	7.37	7.87
C	0.125	0.165	3.18	4.19
D	0.018	0.022	0.46	0.56
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.135	---	3.43	---
V	0.135	---	3.43	---

#### STYLE 1:

1. EMITTER
2. BASE
3. COLLECTOR

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